## NSS40304 MZ4

## Bipolar Power Transistors 40 V, 3.0 A, Low V<sub>CE(sat)</sub> NPN Transistor

ON Semiconductor's e<sup>2</sup>PowerEdge family of low  $V_{CE(sat)}$  transistors are surface mount devices featuring ultra low saturation voltage ( $V_{CE(sat)}$ ) and high current gain capability. These are designed for use in low voltage, high speed switching applications where affordable efficient energy control is important.

Typical applications are DC-DC converters and power management in portable and battery powered products such as cellular and cordless phones, PDAs, computers, printers, digital cameras and MP3 players. Other applications are low voltage motor controls in mass storage products such as disc drives and tape drives. In the automotive industry they can be used in air bag deployment and in the instrument cluster. The high current gain allows e<sup>2</sup>PowerEdge devices to be driven directly from PMU's control outputs, and the Linear Gain (Beta) makes them ideal components in analog amplifiers.

#### **Features**

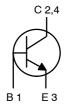
• These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant



#### ON Semiconductor®

http://onsemi.com

# NPN TRANSISTOR 3.0 AMPERES 40 VOLTS, 2.0 WATTS



**Schematic** 

#### MARKING DIAGRAM



SOT-223 CASE 318E STYLE 1



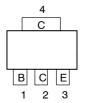
A = Assembly Location

Y Year W = Wo

W = Work Week 40301 = Specific Device Code

= Pb-Free Package

#### **PIN ASSIGNMENT**



Top View Pinout

#### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

#### **查科科·NUM RATINGS** 工作性方向的less otherwise noted)

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V <sub>CEO</sub>	40	Vdc
Collector-Base Voltage	V <sub>CB</sub>	40	Vdc
Emitter-Base Voltage	V <sub>EB</sub>	6.0	Vdc
Base Current - Continuous	I <sub>B</sub>	1.0	Adc
Collector Current - Continuous - Peak	I <sub>C</sub>	3.0 5.0	Adc
Total Power Dissipation Total $P_D @ T_A = 25^{\circ}C$ mounted on 1" sq. (645 sq. mm) Collector pad on FR-4 bd material Total $P_D @ T_A = 25^{\circ}C$ mounted on 0.012" sq. (7.6 sq. mm) Collector pad on FR-4 bd material	P <sub>D</sub>	2.0 0.80	W
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case  - Junction-to-Ambient on 1" sq. (645 sq. mm) Collector pad on FR-4 bd material  - Junction-to-Ambient on 0.012" sq. (7.6 sq. mm) Collector pad on FR-4 bd material	R <sub>θJA</sub> R <sub>θJA</sub>	64 155	°C/W
Maximum Lead Temperature for Soldering Purposes, 1/8" from case for 5 seconds	T <sub>L</sub>	260	°C

#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
NSS40301MZ4T1G	SOT-223 (Pb-Free)	1000 / Tape & Reel
NSS40301MZ4T3G	SOT-223 (Pb-Free)	4000 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

## 直流 TRICAL 3CHARAC TERIS 前CS (T<sub>C</sub> = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit			
OFF CHARACTERISTICS								
Collector–Emitter Sustaining Voltage (I <sub>C</sub> = 10 mAdc, I <sub>B</sub> = 0 Adc)	V <sub>CEO(sus)</sub>	40			Vdc			
Emitter–Base Voltage ( $I_E$ = 50 $\mu$ Adc, $I_C$ = 0 Adc)	V <sub>EBO</sub>	6.0			Vdc			
Collector Cutoff Current (V <sub>CB</sub> = 40 Vdc)	I <sub>CBO</sub>			100	nAdc			
Emitter Cutoff Current (V <sub>BE</sub> = 6.0 Vdc)	I <sub>EBO</sub>			100	nAdc			

#### ON CHARACTERISTICS (Note 1)

	V <sub>CE(sat)</sub>		0.050 0.100 0.200	Vdc
Base–Emitter Saturation Voltage ( $I_C = 1.0  \text{Adc},  I_B = 0.1  \text{Adc}$ )	V <sub>BE(sat)</sub>		1.0	Vdc
Base-Emitter On Voltage (I <sub>C</sub> = 1.0 Adc, V <sub>CE</sub> = 2.0 Vdc)	V <sub>BE(on)</sub>		0.9	Vdc
DC Current Gain	h <sub>FE</sub>	220 200 100	500	

#### **DYNAMIC CHARACTERISTICS**

Output Capacitance (V <sub>CB</sub> = 10 Vdc, f = 1.0 MHz)	C <sub>ob</sub>	25	pF
Input Capacitance (V <sub>EB</sub> = 5.0 Vdc, f = 1.0 MHz)	C <sub>ib</sub>	170	pF
Current-Gain - Bandwidth Product (Note 2) (I <sub>C</sub> = 500 mA, V <sub>CE</sub> = 10 V, F <sub>test</sub> = 1.0 MHz)	f <sub>T</sub>	215	MHz

<sup>1.</sup> Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2%.

<sup>2.</sup>  $f_T = |h_{FE}| \bullet f_{test}$ 

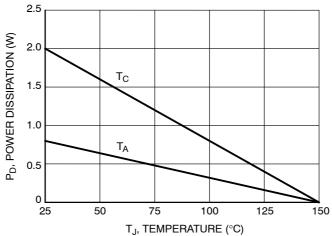


Figure 1. Power Derating

#### 查询"NSS40301MZ4"供应商

#### **TYPICAL CHARACTERISTICS**

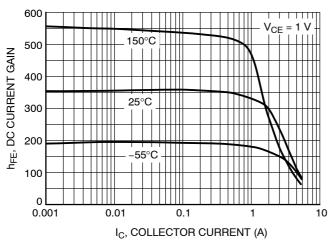


Figure 2. DC Current Gain

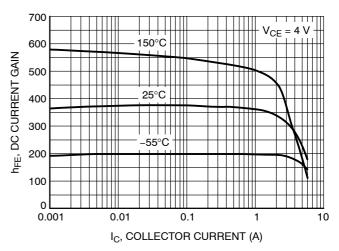


Figure 3. DC Current Gain

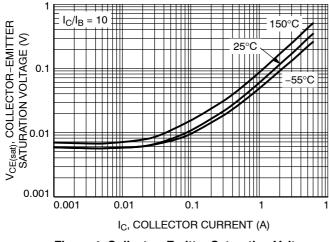


Figure 4. Collector-Emitter Saturation Voltage

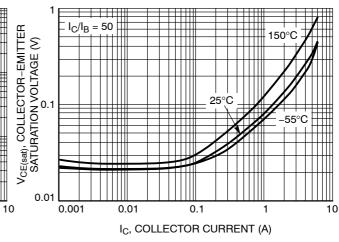


Figure 5. Collector-Emitter Saturation Voltage

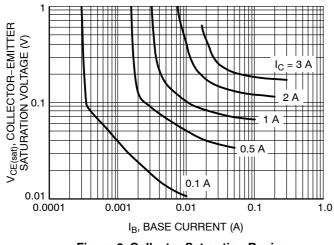


Figure 6. Collector Saturation Region

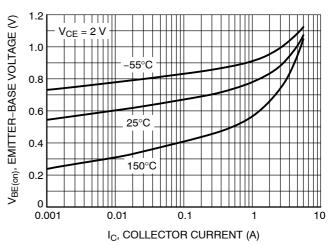


Figure 7. V<sub>BE(on)</sub> Voltage

### 查询"NSS40301MZ4"供应商

#### TYPICAL CHARACTERISTICS

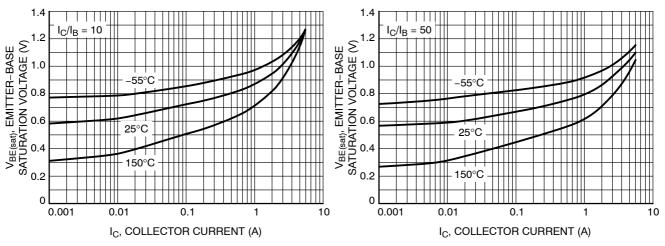


Figure 8. Base-Emitter Saturation Voltage

Figure 9. Base-Emitter Saturation Voltage

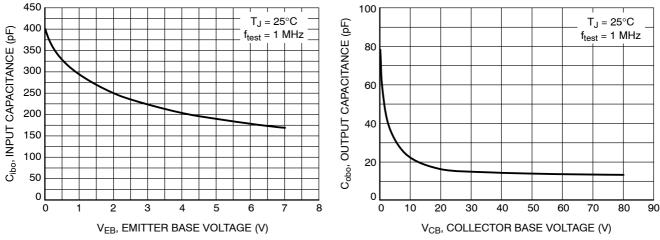


Figure 10. Input Capacitance

Figure 11. Output Capacitance

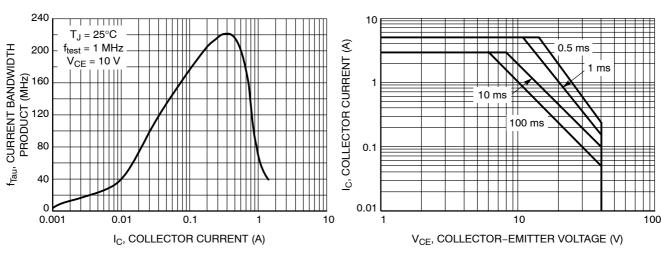


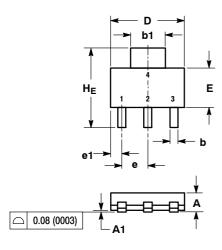
Figure 12. Current-Gain Bandwidth Product

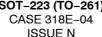
Figure 13. Safe Operating Area

#### 查询"NSS40301MZ4"供应商

#### PACKAGE DIMENSIONS

## SOT-223 (TO-261) CASE 318E-04





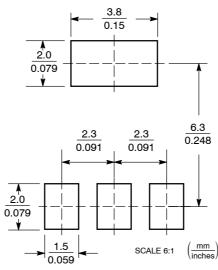
- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
- CONTROLLING DIMENSION: INCH.

	М	ILLIMETE	ETERS INCHES			
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	1.50	1.63	1.75	0.060	0.064	0.068
A1	0.02	0.06	0.10	0.001	0.002	0.004
b	0.60	0.75	0.89	0.024	0.030	0.035
b1	2.90	3.06	3.20	0.115	0.121	0.126
С	0.24	0.29	0.35	0.009	0.012	0.014
D	6.30	6.50	6.70	0.249	0.256	0.263
E	3.30	3.50	3.70	0.130	0.138	0.145
е	2.20	2.30	2.40	0.087	0.091	0.094
e1	0.85	0.94	1.05	0.033	0.037	0.041
L	0.20			0.008		
L1	1.50	1.75	2.00	0.060	0.069	0.078
HE	6.70	7.00	7.30	0.264	0.276	0.287
θ	0°	-	10°	0°	-	10°

## STYLE 1: PIN 1. BASE

- 2. COLLECTOR 3. EMITTER
- 4 COLLECTOR

#### **SOLDERING FOOTPRINT\***



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ON Semiconductor and un are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes without further notice on semiconductor and are registered readerlands of semiconductor Components industries, Ite (SCILLC) as Solitude services are injected in the characteristic or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

#### **PUBLICATION ORDERING INFORMATION**

#### LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor P.O. Box 5163, Denver, Colorado 80217 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada

Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com

N. American Technical Support: 800-282-9855 Toll Free USA/Canada

Europe, Middle East and Africa Technical Support: Phone: 421 33 790 2910 Japan Customer Focus Center

Phone: 81-3-5773-3850

ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative